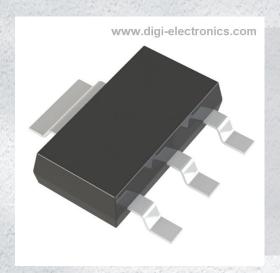


DZT2907A-13 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number DZT2907A-13-DG

Manufacturer Diodes Incorporated

Manufacturer Product Number DZT2907A-13

Description TRANS PNP 60V 0.6A SOT223-3

Detailed Description Bipolar (BJT) Transistor PNP 60 V 600 mA 200MHz 1

W Surface Mount SOT-223-3



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
DZT2907A-13	Diodes Incorporated
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	600 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
60 V	1.6V @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
10nA (ICBO)	100 @ 150mA, 10V
Power - Max:	Frequency - Transition:
1 W	200MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-261-4, TO-261AA	SOT-223-3
Base Product Number:	
DZT2907	

Environmental & Export classification

8541.29.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	







60V PNP SMALL SIGNAL TRANSISTOR IN SOT223

Features

- BVceo > -60V
- Epitaxial Planar Die Construction
- Ideally Suited for Automated Assembly Processes
- Complementary NPN Type: DIODES™ DZT2222A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.112 grams (Approximate)

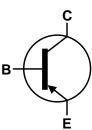
Applications

Medium power amplification and switching

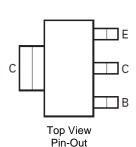




Top View



Device Symbol



Ordering Information (Note 4)

Part Number	Packago	Marking Reel Size (inches)		Tape Width (mm)	Packing	
Part Number	Package	Warking	Reel Size (Iliches)	rape widin (mm)	Qty.	Carrier
DZT2907A-13	SOT223	K2F	13	12	2,500	Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT223



K2F = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 3 = 2023) WW = Week Code (01 to 52)

DZT2907A

Document number: DS30921 Rev. 6 - 2

1 of 8 www.diodes.com



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vcво	-60	V
Collector-Emitter Voltage	Vceo	-60	V
Emitter-Base Voltage	VEBO	-5	V
Collector Continuous Current	Ic	-600	mA
Peak Collector Current	Ісм	-800	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

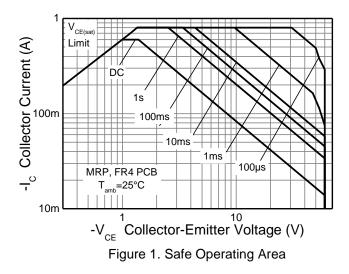
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	0.83	W
Thermal Resistance, Junction to Ambient Air (Note 5)	R _θ JA	150	°C/W
Power Derating Factor above +25°C (Note 5)	P _{DER}	6.66	mW/°C
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Note:

^{5.} For a device mounted on minimum recommended pad (MRP) layout that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.



Thermal Characteristics and Derating Information



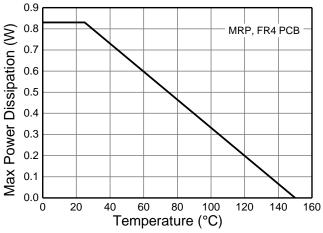


Figure 2. Derating Curve

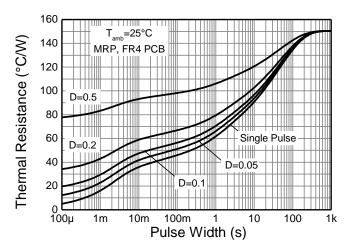


Figure 3. Transient Thermal Impedance

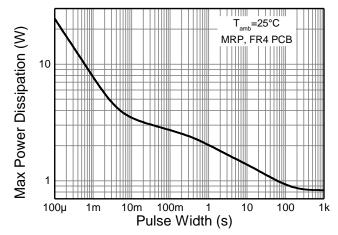


Figure 4. Pulse Power Dissipation



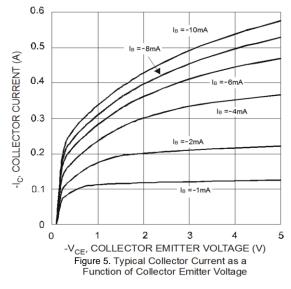
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions	
OFF CHARACTERISTICS (Note 6)							
Collector-Base Breakdown Voltage	BV _{CBO}	-60		-	V	$I_C = -10\mu A$	
Collector-Emitter Breakdown Voltage	BVceo	-60		-	V	Ic = -10mA	
Emitter-Base Breakdown Voltage	BV _{EBO}	-5		-	V	I _E = -10μA	
	I _{CBO}	_	1	-0.01	μA	V _{CB} = -50V	
Collector-Base Cutoff Current		_	_	-10		V _{CB} = -50V, T _A = +150°C	
Collector Cutoff Current	ICEX	_	_	-50	nA	Vce = -30V, Veb(off) = -0.5V	
Base Cutoff Current	I _{BL}	_		-50	nA	Vce = -30V, Veb(off) = -0.5V	
ON CHARACTERISTICS (Note 6)							
Callantan Fasittan Catamatian Valtana	Voru	_	_	-0.4	V	Ic = -150mA, I _B = -15mA	
Collector-Emitter Saturation Voltage	VCE(sat)	_	_	-1.6	V	Ic = -500mA, I _B = -50mA	
		75	_	-	_	Vcε = -10V, Ic = -100μA	
		100		-	_	$V_{CE} = -10V, I_{C} = -1mA$	
DC Current Gain	hFE	100	_	_	_	V _{CE} = -10V, I _C = -10mA	
		100	_	300	_	VcE = -10V, Ic = -150mA	
		50		-	_	VcE = -10V, Ic = -500mA	
Dana Fasittan Oatomatian Waltana	V _{BE} (sat)		_	-1.3	V	Ic = -150mA, I _B = -15mA	
Base-Emitter Saturation Voltage		_	_	-2.6	V	Ic = -500mA, I _B = -50mA	
SMALL SIGNAL CHARACTERISTICS							
Current Gain-Bandwidth Product	f⊤	200	_	_	MHz	VcE = -20V, Ic = -50mA, f = 100MHz	
Output Capacitance	Cobo		—	8	pF	V _{CB} = -10V, f = 1MHz	
Input Capacitance	C _{ibo}	_	—	30	pF	V _{EB} = -2V, f = 1MHz	
SWITCHING CHARACTERISTICS							
Turn-On Time	ton	_	_	45	ns		
Delay Time	td	_	_	10	ns	Vcc = -30V, Ic = -150mA, I _{B1} = -15mA	
Rise Time	tr	_		40	ns		
Turn-Off Time	t _{off}	_	—	100	ns	Vcc = -6V, Ic = -150mA,	
Storage Time	ts	_	—	80	ns	VCC = -6V, $IC = -150MA$, $IB_1 = -IB_2 = -15MA$	
Fall Time	tf	_	_	30	ns	151 - 152 - 1511174	

Note: 6. Measured under pulsed conditions. Pulse width \leqslant 300µs. Duty cycle \leqslant 2%.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



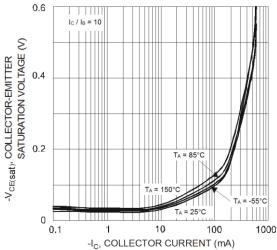
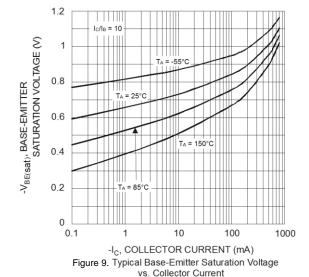


Figure 7. Typical Collector-Emitter Saturation Voltage vs. Collector Current



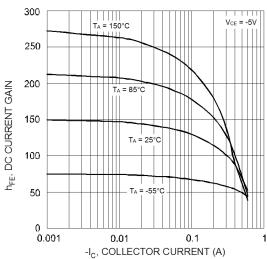


Figure 6. Typical DC Current Gain vs. Collector Current

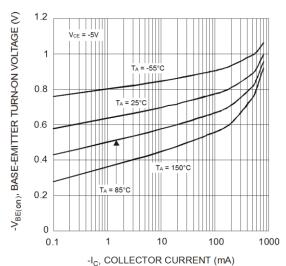


Figure 8. Typical Base-Emitter Turn-On Voltage vs. Collector Current

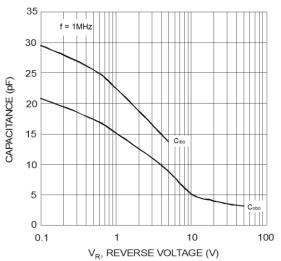


Figure 10. Typical Capacitance Characteristics



Typical Electrical Characteristics (continued)

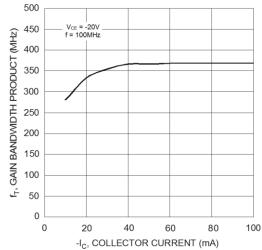


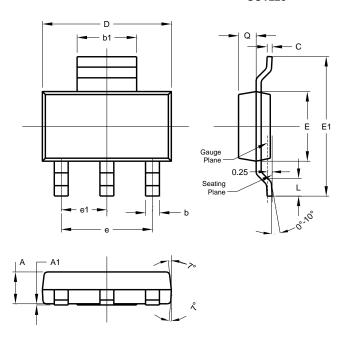
Figure 11. Typical Gain-Bandwidth Product vs. Collector Current



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223

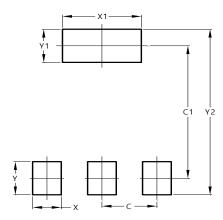


SOT223				
Dim	Min	Max	Тур	
Α	1.55	1.65	1.60	
A1	0.010	0.15	0.05	
b	0.60	0.80	0.70	
b1	2.90	3.10	3.00	
C	0.20	0.30	0.25	
D	6.45	6.55	6.50	
Е	3.45	3.55	3.50	
E1	6.90	7.10	7.00	
е	-	-	4.60	
e1	-	-	2.30	
L	0.85	1.05	0.95	
Q	0.84	0.94	0.89	
All Dimensions in mm				

Suggested Pad Layout

 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

SOT223



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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